NSN 5961-01-050-1013

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View Online at https://aerobasegroup.com/nsn/5961-01-050-1013 **Inclosure Material:** Metal **Overall Length:** 1.250 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to emitter voltage/static/base open and 60.0 collector to emitter reverse voltage and 90.0 collector to base voltage, dc and 7.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: